











CSD25501F3

SLPS692 - OCTOBER 2017

CSD25501F3 -20-V P-Channel FemtoFET™ MOSFET

Features

- Low On-Resistance
- Ultra-Low Q_q and Q_{qd}
- Ultra-Small Footprint
 - 0.7 mm × 0.6 mm
- Low Profile
 - 0.22-mm Max Height
- Integrated ESD Protection Diode
- Lead and Halogen Free
- **RoHS Compliant**

Applications

- Optimized for Load Switch Applications
- **Battery Applications**
- Handheld and Mobile Applications

Description

This -20-V, 64-m Ω , P-Channel FemtoFET™ MOSFET is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing a substantial reduction in footprint size. The integrated $10-k\Omega$ clamp resistor (R_C) allows the gate voltage (V_{GS}) to be operated above the maximum internal gate oxide value of -6 V depending on duty cycle. The gate leakage (I_{GSS}) through the diode increases as V_{GS} is increased above -6 V.

Typical Part Dimensions 0.7 mm 0.6 mm

Product Summary

$T_A = 25^\circ$	С	TYPICAL VA	UNIT		
V_{DS}	Drain-to-Source Voltage -20				
Q_g	Gate Charge Total (–4.5 V) 1.02				
Q_{gd}	Gate Charge Gate-to-Drain	0.09	nC		
		$V_{GS} = -1.8 \text{ V}$	120		
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = -2.5 V	86	mΩ	
	CH Productinos	$V_{GS} = -4.5 \text{ V}$	64		
V _{GS(th)}	Threshold Voltage	-0.75	V		

Device Information⁽¹⁾

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD25501F3	3000		Femto	Tape
CSD25501F3T	250	7-Inch Reel	0.73-mm × 0.64-mm Land Grid Array (LGA)	and Reel

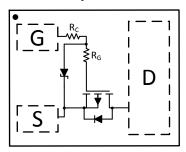
(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

	7 10001010 1110711110111 110111190									
T _A = 25	T _A = 25°C (unless otherwise stated) VALUE									
V_{DS}	Drain-to-Source Voltage	-20	٧							
V_{GS}	Gate-to-Source Voltage	-20	٧							
I _D	Continuous Drain Current ⁽¹⁾	-3.6	Α							
I _{DM}	Pulsed Drain Current ⁽¹⁾⁽²⁾	-13.6	Α							
P _D	Power Dissipation ⁽¹⁾	500	mW							
V	Human-Body Model (HBM)	4000	V							
V _(ESD)	Charged-Device Model (CDM)	2000	V							
T _J , T _{stg}	Operating Junction, Storage Temperature	-55 to 150	°C							

- (1) Typical $R_{\theta JA}$ = 255°C/W mounted on FR4 material with minimum Cu mounting area.
- (2) Pulse duration ≤ 100 μs, duty cycle ≤ 1%.

Top View



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4 Revision History

DATE	REVISION	NOTES
October 2017	*	Initial release.

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5 Specifications

5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV _{DSS}	Drain-to-source voltage	$V_{GS} = 0 \text{ V}, I_{DS} = -250 \mu\text{A}$	-20			V
I _{DSS}	Drain-to-source leakage current	V _{GS} = 0 V, V _{DS} = -16 V			-50	nA
	Coto to course legisers correct	V _{DS} = 0 V, V _{GS} = -6 V			-50	nA
I_{GSS}	Gate-to-source leakage current	$V_{DS} = 0 \text{ V}, V_{GS} = -16 \text{ V}$			-1	mA
V _{GS(th)}	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_{DS} = -250 \mu A$	-0.45	-0.75	-1.05	V
		$V_{GS} = -1.8 \text{ V}, I_{DS} = -0.1 \text{ A}$		120	260	
R _{DS(on)}	Drain-to-source on-resistance	$V_{GS} = -2.5 \text{ V}, I_{DS} = -0.4 \text{ A}$		86	125	$m\Omega$
		$V_{GS} = -4.5 \text{ V}, I_{DS} = -0.4 \text{ A}$		64	76	
g _{fs}	Transconductance	$V_{DS} = -2 \text{ V}, I_{DS} = -0.4 \text{ A}$		3.4		S
DYNAMI	C CHARACTERISTICS					
C _{iss}	Input capacitance			295	385	pF
C _{oss}	Output capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = -10 \text{ V},$ f = 100 kHz		70	91	pF
C _{rss}	Reverse transfer capacitance) = 100 KHZ		4.1	5.3	pF
R _G	Series gate resistance			33		Ω
R_C	Series clamp resistance			10,000		Ω
Qg	Gate charge total (-4.5 V)			1.02	1.33	nC
Q_{gd}	Gate charge gate-to-drain	V 10 V 1 0 4 A		0.09		nC
Q _{gs}	Gate charge gate-to-source	$V_{DS} = -10 \text{ V}, I_{DS} = -0.4 \text{ A}$		0.45		nC
Q _{g(th)}	Gate charge at V _{th}			0.36		nC
Q _{oss}	Output charge	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}$		1.8		nC
t _{d(on)}	Turnon delay time			474		ns
t _r	Rise time	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$		428		ns
$t_{d(off)}$	Turnoff delay time	$I_{DS} = -0.4 \text{ A}, R_G = 0 \Omega$		1154		ns
t _f	Fall time	94		945		ns
DIODE C	CHARACTERISTICS					
V _{SD}	Diode forward voltage	$I_{SD} = -0.4 \text{ A}, V_{GS} = 0 \text{ V}$		-0.73	-0.95	V
Q _{rr}	Reverse recovery charge	V = 40 V I = 0.4 A di/dt 200 A/ =		3.0		nC
t _{rr}	Reverse recovery time	$V_{DS} = -10 \text{ V}, I_F = -0.4 \text{ A}, \text{ di/dt} = 200 \text{ A/}\mu\text{s}$		7.4		ns

5.2 Thermal Information

 $T_A = 25$ °C (unless otherwise stated)

	THERMAL METRIC	TYPICAL VALUES	UNIT
D	Junction-to-ambient thermal resistance ⁽¹⁾	90	°C/W
$R_{\theta JA}$	Junction-to-ambient thermal resistance (2)	255	°C/W

⁽¹⁾ Device mounted on FR4 material with 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu.

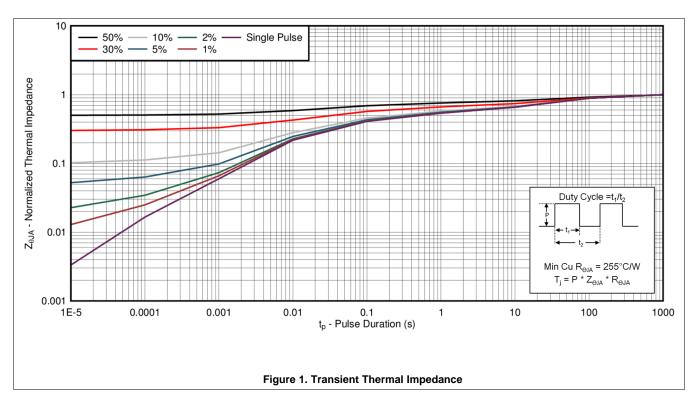
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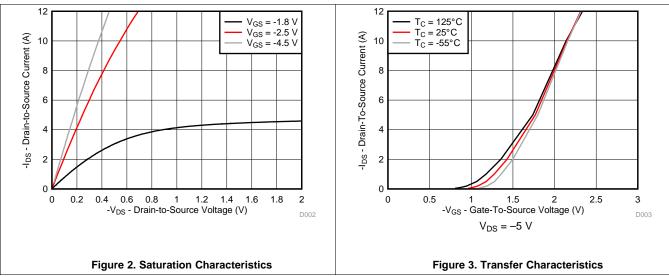
⁽²⁾ Device mounted on FR4 material with minimum Cu mounting area.

TEXAS INSTRUMENTS

5.3 Typical MOSFET Characteristics

 $T_A = 25$ °C (unless otherwise stated)



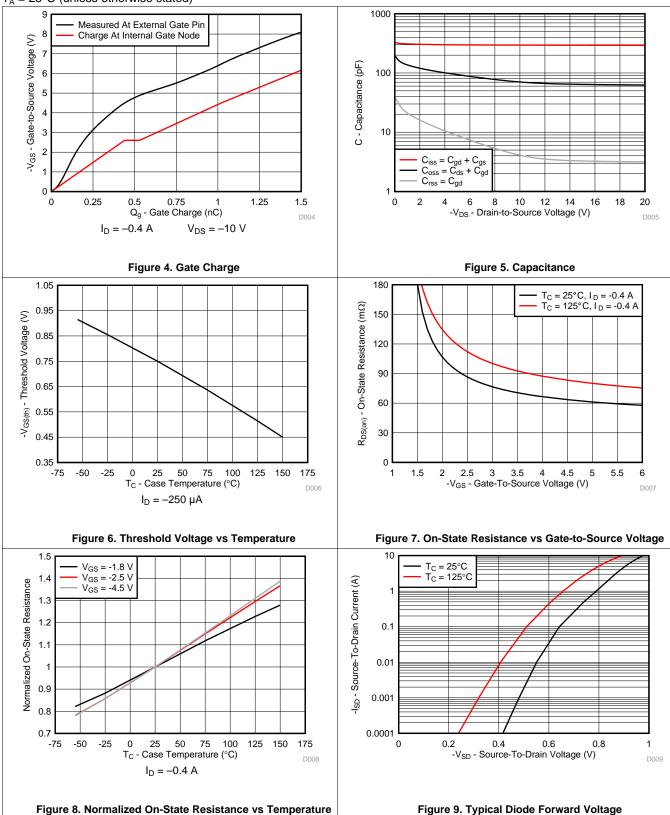




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Typical MOSFET Characteristics (continued)

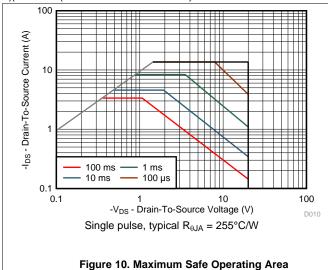
 $T_A = 25$ °C (unless otherwise stated)



TEXAS INSTRUMENTS

Typical MOSFET Characteristics (continued)

 $T_A = 25$ °C (unless otherwise stated)



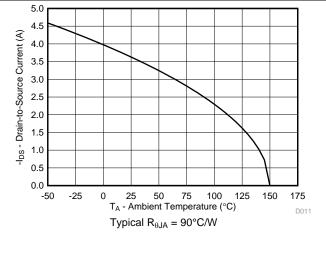


Figure 11. Maximum Drain Current vs Temperature

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6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

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6.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGE OPTION ADDENDUM

13-Oct-2017

PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD25501F3	ACTIVE	PICOSTAR	YJN	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	V	Samples
CSD25501F3T	ACTIVE	PICOSTAR	YJN	3	250	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	V	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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